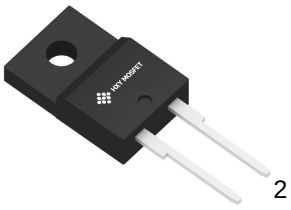
DSC08A065FP

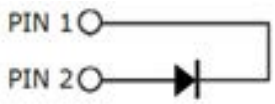
Silicon Carbide Schottky Diode

Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F



TO-220F-2L



Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

Part Number	Package	Qty(PCS)
DSC08A065FP	TO-220F-2L	50

Maximum Ratings (T_C = 25 ˚C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V_{RRM}	Repetitive Peak Reverse Voltage	650	V	
V_{RSM}	Surge Peak Reverse Voltage	650	V	
I_F	Continuous Forward Current	17.7 9.2 8	A	T_C=25˚C T_C=125˚C T_C=135.5˚C
I_{FRM}	Repetitive Peak Forward Surge Current	30	A	T_C=25˚C, t_P = 10 ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	60	A	T_C=25˚C, t_p = 10 ms, Half Sine Wave
P_{tot}	Power Dissipation	57 25	W	T_C=25˚C T_C=110˚C
T_J , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	˚C	
	TO-220 Mounting Torque	1	Nm	M3 Screw
$\int i^2dt$	i²dt value	18	A^2s	T_C=25˚C, t_p = 10 ms, Half Sine Wave

Electrical Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{DC}	DC Blocking Voltage	650			V	
V_F	Forward Voltage		1.42 1.88	1.7 2.5	V	I_F = 8 A T_J=25°C I_F = 8 A T_J=175°C
I_R	Reverse Current		0.12 0.91	50 100	μA	V_R = 650 V T_J=25°C V_R = 650 V T_J=175°C
Q_C	Total Capacitive Charge		21		nC	V_R = 400 V T_J = 25°C
C	Total Capacitance		395 42 41		pF	V_R = 0 V, T_J = 25°C, f = 1 MHz V_R = 200 V, T_J = 25°C, f = 1 MHz V_R = 400 V, T_J = 25°C, f = 1 MHz
E_C	Capacitance Stored Energy		5		μJ	V_R = 400 V

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	2.61	°C/W

Typical Performance

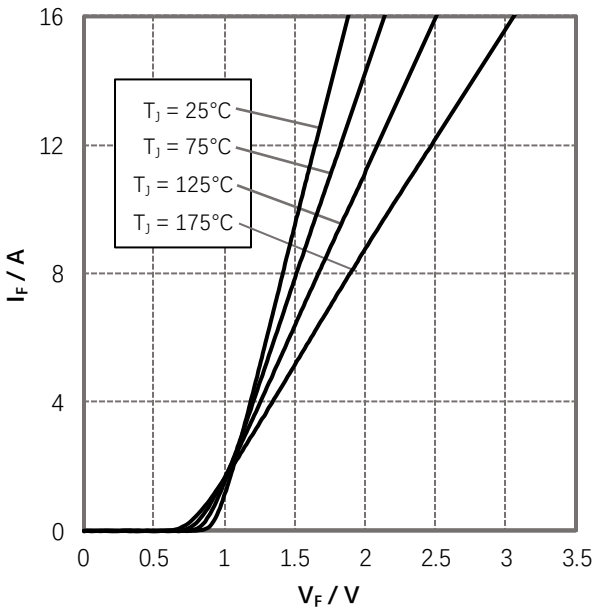


Figure 1. Forward Characteristics

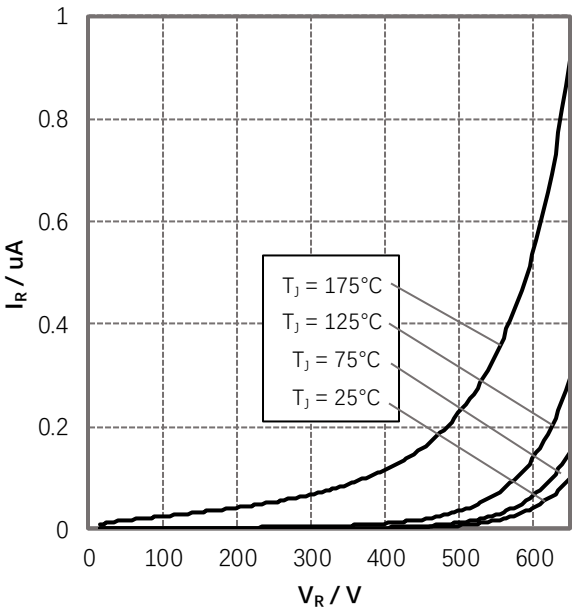


Figure 2. Reverse Characteristics

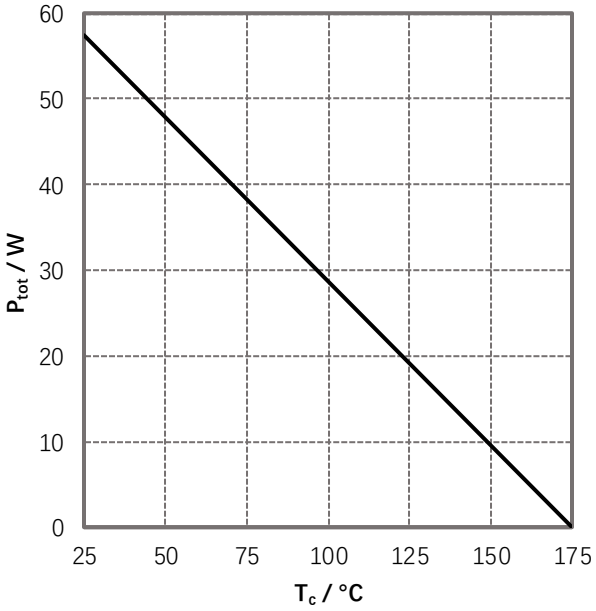


Figure 3. Power Derating

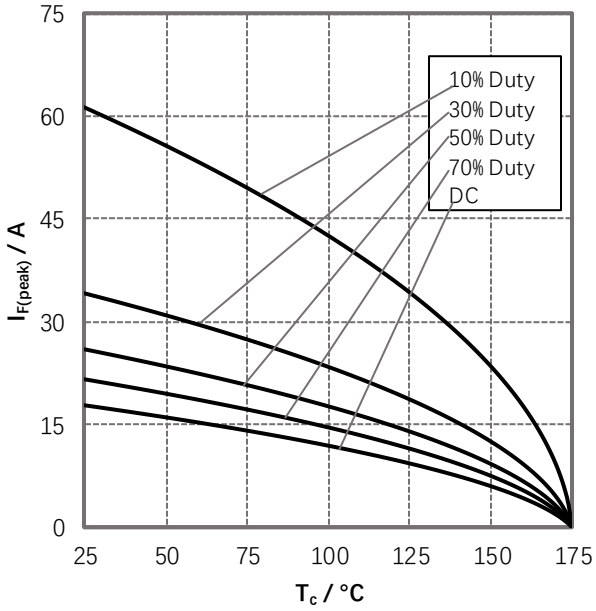


Figure 4. Current Derating

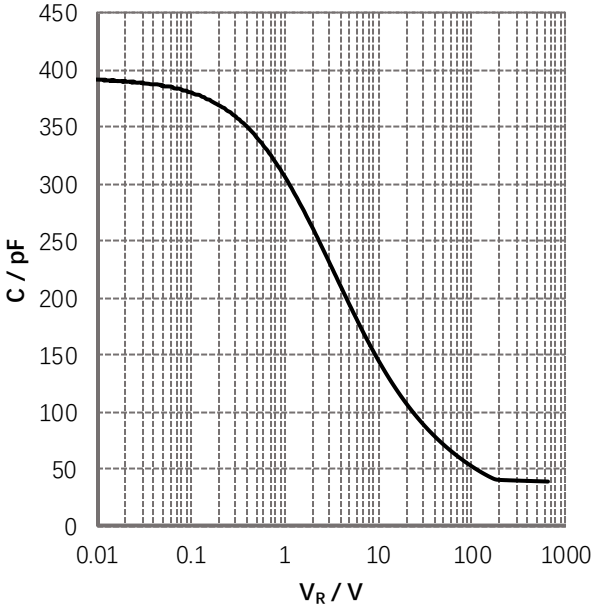


Figure 5. Capacitance vs. Reverse Voltage

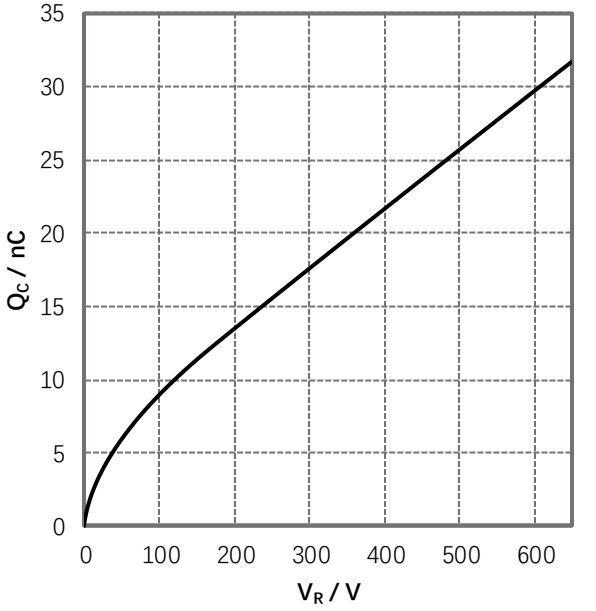


Figure 6. Total Capacitance Charge vs. Reverse Voltage

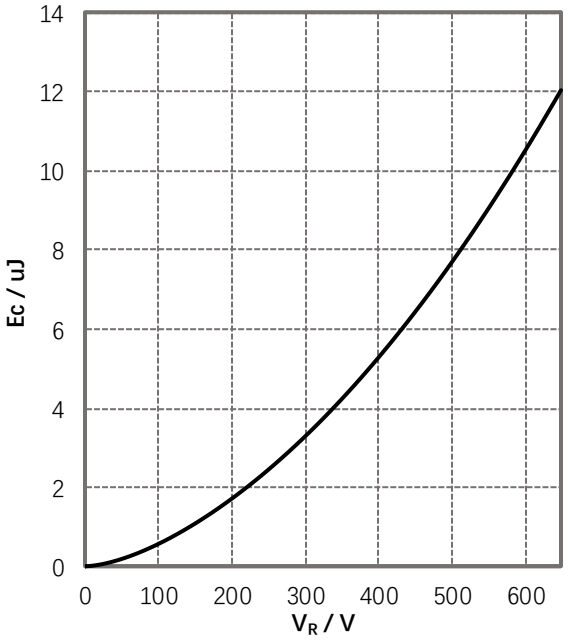


Figure 7. Capacitance Stored Energy

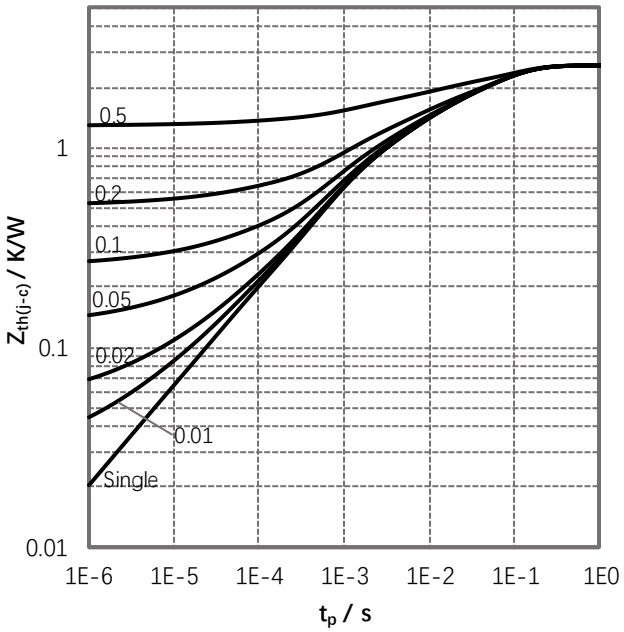
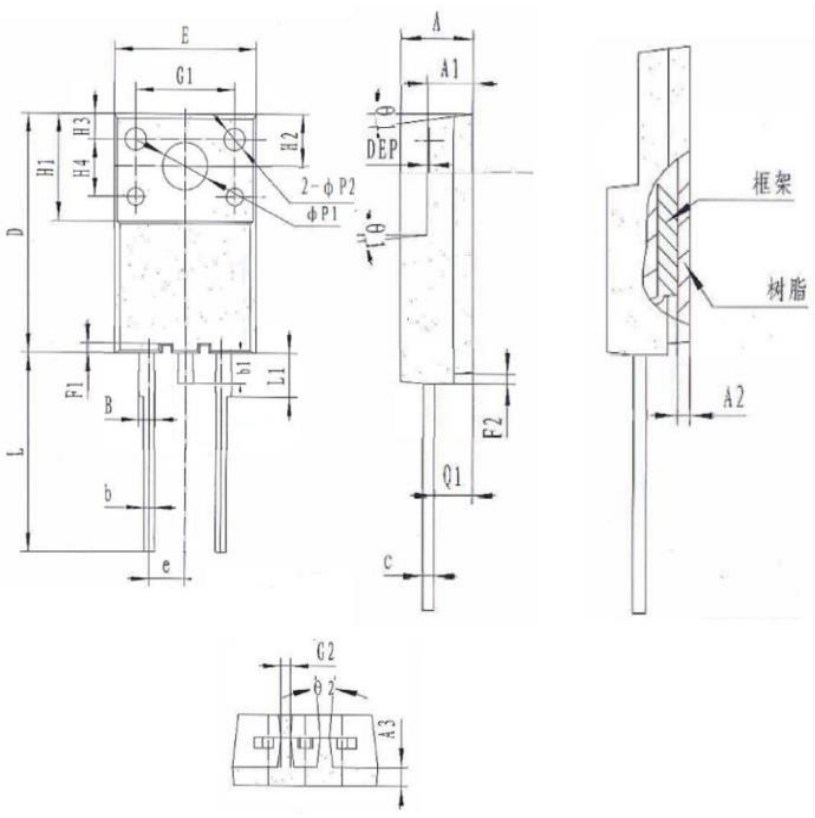


Figure 8. Transient Thermal Impedance

Package Information
TO-220F-2L



项目	规范(mm)	
	MIN	MAX
A	4.30	4.70
A1	2.68	2.88
A2	0.55	0.65
A3	0.86	1.06
b	0.77	0.87
b1	0.60	0.80
B	1.07	1.25
c	0.45	0.55
D	15.70	16.10
E	9.90	10.22
F1	0.40	0.60
F2	0.50	0.70
G1	6.90	7.10
G2	0.60	0.70
H1	6.80	7.20
H2	3.25	3.45
H3	1.50	1.90
H4	3.65	4.05
e	2.49	2.59
L	13.00	13.60
L1	3.20	3.40
Q1	2.20	2.40
θ1	4°	10°
θ2	7°	13°
ϕP1	3.06	3.26
ϕP2	1.40	1.60
DEP	0.05	0.20

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